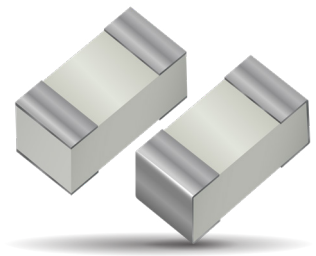
Q Bridge Thermal Conductor



GENERAL DESCRIPTION

A\/X's new Q-Bridge Thermal Conductor is manufactured with the highest quality materials for reliable and repeatable performance providing a cost effective thermal management solution. These devices are constructed with Aluminum Nitride (AlN) or Beryllium Oxide (BeO) and are available in standard EIA form factors.

Q-Bridge provides the designer with the ability to manage thermal conditions by directing heat to a thermal ground plane, heat sink or any other specific thermal point of interest. The inherently low capacitance makes this device virtually transparent at RF/microwave frequencies. This device has the added benefit of offering additional layers of protection to adjacent components from hot spot thermal loads.

Q-Bridge provides the benefit of increased overall circuit reliability. A\/X's Q-Bridge is manufactured using one-piece construction, providing a RoHS compliant SMT package that is fully compatible with high speed automated pick-andplace processing. It is available in multiple different EIA case sizes. Custom configurations are also available

APPLICATIONS

- High Thermal Conductivity
- Low Thermal Resistance
- Low Capacitance
- Increases Circuit Reliability
- RoHS Compliant
- More efficient thermal management

FEATURES

- GaN Power Amplifiers
- High RF Power Amplifiers
- Filters
- Synthesizers
- Industrial Computers
- Switch Mode Power Supplies
- Pin & Laser Diodes

FUNCTIONAL APPLICATIONS

- Between active device and adjacent ground planes
- Specific contact pad to case
- Contact pad to contact pad
- Direct component contact to via pad or trace
- Edges fully metalized

HOW TO ORDER

QB 0603 A 25 W Y T

Q-Bridge

Case Size
Please see 'Case Size' Column of Typical Characteristics Table Below

Substrate
A = AlN
B = BeO

Thickness
(mils)

Packaging
T = 1000pcs., 7" reel
T\500 = 500pcs., 7" reel
C = Matrix Tray

Termination
Y = Silver Platinum, Non-Magnetic Termination
S = Silver over Magnetic Termination
J* = 60Sn/40Pb Solder Plated over Nickel over Silver Platinum
T = Tin plated over Nickel over Silver Platinum
* Not RoHS Compliant
Consult factory for other termination options e.g., tin plate and solder plate

Style
W = Edge Wrap
E = No Wrap

RoHS COMPLIANT

TERMINATION MATERIALS

AVX Termination Code	Termination Materials	
T	Tin plated over Nickel over Silver Platinum	RoHS Compliant
Y	Silver Platinum Non-Magnetic Termination	RoHS Compliant
S	Silver over Magnetic Termination	RoHS Compliant
J	Solder Plated over Nickel over Silver Platinum	Not RoHS Compliant

Note: Non-edge wrapped style in all case sizes is supplied with S termination
Edge wrapped style in case sizes 0302 through 1111 is supplied with S termination
Edge wrapped style in case sizes 2010 through 3737 are supplied with S termination

The above part number refers to a Q-Bridge, (EIA case size 0603), Aluminum Nitride Substrate, Thickness 25 mils., Style W, Y Termination (Silver Platinum Non-Magnetic Termination), with Tape and Reel Packaging.

Q Bridge Thermal Conductor

TYPICAL CHARACTERISTICS

Case Size	Length (L)	Width (W)	Thickness (T)	Terminal (t)	Thermal Resistance (°C/W)		Thermal Conductivity (mW/°C)		Available Configurations	
					AlN	BeO	AlN	BeO	Style	Termination
0302	.030 ± .002 (.77 ± .051)	.020 ± .002 (0.51 ± .051)	20 (0.51 ± .05)	10 (0.25)	19	12	53	81	W	Y, T, J
									E	S
0402	.040 ± .002 (1.02 ± .051)	.020 ± .002 (0.51 ± .051)	20 (0.51 ± .05)	10 (0.25)	25	16	40	61	W	Y, T, J
									E	S
0505	.050 ± .002 (1.27 ± .051)	.050 ± .002 (1.27 ± .051)	25 (0.64 ± .05)	15 (0.38)	10	7	100	153	W	Y, T, J
									E	S
0603	.060 ± .002 (1.52 ± .051)	.030 ± .002 (.77 ± .051)	25 (0.64 ± .05)	15 (0.38)	20	13	50	76	W	Y, T, J
									E	S
0805	.080 ± .002 (2.03 ± .051)	.050 ± .002 (1.27 ± .051)	40 (1.02 ± .05)	20 (0.51)	10	7	100	153	W	Y, T, J
									E	S
1005	.100 ± .002 (2.54 ± .051)	.050 ± .002 (1.27 ± .051)	40 (1.02 ± .05)	20 (0.51)	13	8	77	122	W	Y, T, J
									E	S
1020	.100 ± .002 (2.54 ± .051)	.200 ± .002 (5.08 ± .051)	40 (1.02 ± .05)	20 (0.51)	3	2	320	508	W	Y, T, J
									E	S
1111	.110 ± .002 (2.79 ± .051)	.110 ± .002 (2.79 ± .051)	40 (1.02 ± .05)	20 (0.51)	7	4	153	240	W	Y, T, J
									E	S
2010	.195 ± .010 (4.95 ± .254)	.095 ± .010 (2.41 ± .254)	60 (1.52 ± .05)	30 (0.77)	10	6	100	159	W	S
									E	S
2525	.240 ± .010 (6.10 ± .254)	.250 ± .010 (6.35 ± .254)	60 (1.52 ± .05)	40 (1.02)	4	3	240	380	W	S
									E	S
3725	.370 ± .010 (9.40 ± .254)	.245± .010 (6.22 ± .254)	60 (1.52 ± .05)	50 (1.27)	6	4	160	254	W	S
									E	S
3737	.365 ± .010 (9.27 ± .254)	.375 ± .010 (9.53 ± .254)	60 (1.52 ± .05)	50 (1.27)	4	3	240	380	W	S
									E	S

Inches (mm)

Note: Thermal conductivity is normalized to chip size. All values are approximate. Consult factory for extended thermal conductivity options.

CAPACITANCE

Case Size	Part Number	Capacitance (pF)	Case Size	Part Number	Capacitance (pF)
0302	QB0302A20WY/T/J	0.039	1020	QB1020A40W	0.204
	QB0302A20ES	0.011		QB1020A40ES	0.121
	QB0302B20WY/T/J	0.028		QB1020B40W	0.158
	QB0302B20ES	0.006		QB1020B40ES	0.092
0402	QB0402A20WY/T/J	0.028	1111	QB1111A40W	0.096
	QB0402A20ES	0.018		QB1111A40ES	0.042
	QB0402B20WY/T/J	0.025		QB1111B40W	0.078
	QB0402B20ES	0.009		QB1111B40ES	0.031
0505	QB0505A20WY/T/J	0.070	2010	QB2010A60WY/T/J	0.070
	QB0505A20ES	0.032		QB2010A60ES	0.042
	QB0505B20WY/T/J	0.061		QB2010B60WY/T/J	0.055
	QB0505B20ES	0.027		QB2010B60ES	0.086
0603	QB0603A25/WY/T/J	0.035	2525	QB2525A60WY/T/J	0.156
	QB0603A25ES	0.007		QB2525A60ES	0.114
	QB0603B25WY/T/J	0.029		QB2525B60WY/T/J	0.122
	QB0603B25ES	0.007		QB2525B60ES	0.075
0805	QB0805A40WY/T/J	0.081	3725	QB3725A60WY/T/J	0.105
	QB0805A40ES	0.018		QB3725A60ES	0.076
	QB0805B40W	0.055		QB3725B60WY/T/J	0.080
	QB0805B40ES	0.015		QB3725B60ES	0.058
1005	QB1005A40WY/T/J	0.046	3737	QB3737A60W	0.164
	QB1005A40ES	0.008		QB3737A60ES	0.130
	QB1005B40W	0.038		QB3737B60WY/T/J	0.126
	QB1005B40ES	0.007		QB3737B60ES	0.099